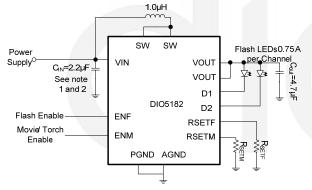


## DIO5182 2MHz, 1.5A Flash LED Driver

#### **Features**

- Dual Flash LED Outputs
- Drive Up to Total 1.5A or 0.75A per Channel
- Up to 90% Efficiency
- Integrated 2MHz Step-Up Converter
- 3V to 5V Operation Voltage Range
- Very Small Inductor: 1.0μH
- Independent Flash Mode Enable and Movie/Torch Mode Enable Pins
- PWM Dimming for Movie/Torch Mode
- One Resistor Sets Flash Mode LED Current
- One Resistor Sets Movie/Torch Mode LED Current
- Integrated Thermal Regulation Control
- LED Current Linearly Reduces to 1/2 of LED Current Setting Automatically When V<sub>IN</sub> is in 3.3V to 3.4V Range
- 600ms Flash Timer Control
- 330kΩ Pull-Down Resistor on ENM and ENF Pins
- LED Open or Short Protection
- Output Over-Voltage Protection
- Cycle-by-Cycle Inductor Current Limit
- 0.1µA Shutdown Current
- Available in Green DFN-3×2-14L Package
- -40°C to +85°C Operating Temperature Range

### **Typical Applications**



#### Note:

- 1: The decoupling capacitor  $C_{\text{IN}}$  at the input should be placed as close as possible to VIN pin.
- 2: The power supply is recommended to be routed to VIN pin first with capacitor closely placed, then routed to inductors and then to SW pin.

### **Descriptions**

DIO5182 is a Boost-architecture high power flash LED driver, ideally for smart phone camera modules or digital still camera modules. The internal DC/DC switch works at 2MHz and needs few peripheral components, fitting for portable photo flash solution.

DIO5182 has independent Flash mode and Movie/Torch mode enable pins. Flash mode is usually used with 660ms timer control to generate a high intensity flash. The Flash mode and Movie/Torch mode LED current is programmed by external resistors respectively, making the flash LED solution simple to control. If both enable pins are at logic high, the LED current will be programmed by the Movie/Torch mode setting resistor.

In order to protect battery system, DIO5182 can adjust the LED current to half of LED current setting by external resistor automatically when VIN is lower than 3.4V, then DIO5182 can reduce the current from battery in low voltage status.

DIO5182 has many protection features, including cycle-by-cycle input current limit protection, output over-voltage protection, LED fault (open or short) protection and thermal shutdown protection. The leakage current in shutdown is 0.1µA. DIO5182 is available in Green DFN-3×2-14L package. It operates over an ambient temperature range of -40°C to +85°C.

### **Applications**

- Single Cell Li-Battery Powered Products
- Portable Audio Players
- Cellular Phones
- Personal Medical Products



# **Ordering Information**

Order Part Number	Top Marking		T <sub>A</sub>	Package	
DIO5182CD14	D5182	Green	-40 to +85°C	DFN-3×2-14L	Tape & Reel, 3000

## **Pin Assignments**

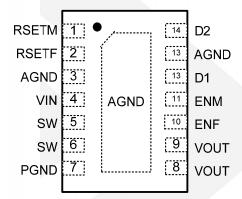


Figure 1 Pin Assignment (Top View)

## **Pin Definitions**

PIN	Pin Name	Description
1	RSETM	Movie and Torch Mode Current Setting Pin
2	RSETF	Flash Mode Current Setting Pin
3,13	AGND	Analog Ground Pin
4	VIN	Input Supply Pin for the IC
5,6	SW	Switching Node of the Step-Up Converter
7	PGND	Power Ground Pin.
8,9	VOUT	Output Voltage Pin.
10	ENF	Flash Mode Enable Pin. This pin has an internal 330k pull-down resistor to AGND
11	ENM	Movie/Torch Mode Enable Pin. This pin has an internal 330k pull-down resistor to AGND
12	D1	Regulated Output Sink Current. Up to 0.75A current. D1 and D2 pins can be connected together
14	D2	to sink 1.5A combined.
Exposed pad	AGND	Connected to ground for electrical and thermal usage. Exposed pad is Pad internally connected to analog ground pin.



## **Absolute Maximum Ratings**

Stresses beyond those listed under "Absolute Maximum Rating" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maxim rating conditions for extended periods may affect device reliability.

Parameter	Rating	Unit
VIN, VOUT, D1 and D2 voltage	-0.3 to 6	V
ENF, ENM, RSETF, RSETM	-0.3 to V <sub>IN</sub> +0.3	V
SW voltage	-0.3 to 6.5	V
Junction Temperature	150	°C
Storage Temperature	-65 to 150	°C
Lead Temperature (soldering, 10s)	260	°C
ESD (HBM)	4000	V
ESD (MM)	200	V

## **Recommend Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended Operating conditions are specified to ensure optimal performance to the datasheet specifications. DIOO does not Recommend exceeding them or designing to Absolute Maximum Ratings.

Parameter	Rating	Unit	
Input Supply Voltage	3 to 5	V	
Operating Temperature Range	-40 to 85	°C	



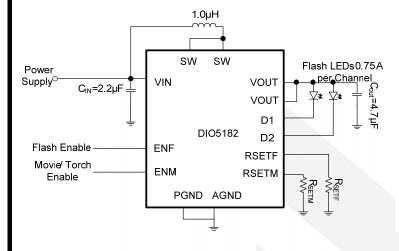
## **Electrical Characteristics**

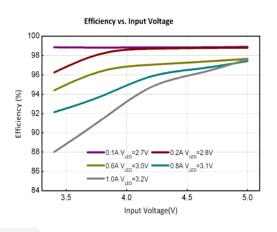
 $(V_{IN} = V_{EN} = 3.6V$ , typical values at +25°C, unless otherwise noted.)

Parameter	Symbol	Conditions	Min	Тур	Max	Uni
IC Supply						
Input Voltage Range	V <sub>IN</sub>		3		5	V
Under-Voltage Lockout Threshold	UVLO	Rising edge		2.4		٧
Under-Voltage Lockout Hysteresis	V <sub>HYS</sub>			0.24		V
Supply Current	IQ	Not switching		350		μA
Supply Current in Shutdown	I <sub>SHDN</sub>	ENF=ENM=GND		0.1		μA
Step-up Converter			l	l.	ľ	ı
Oscillator Frequency	f <sub>S</sub>			2		МН
Maximum Duty Cycle	D <sub>MAX</sub>			75		%
Internal Over-Voltage Threshold of OUT	V <sub>OVP</sub>			5.3		V
Flash Mode Soft-Start Time	ts			1		ms
Current Sink			l .	I.	l.	ı
Total Output Current, Movie/Torch Mode		ENM=HIGH, $R_{SETM}$ =75k $\Omega$ , D1+D2, $T_A$ =25°C		200		m/
Total Output Current, Flash Mode	I <sub>D</sub>	ENF=HIGH, ENM=GND, R <sub>SETF</sub> =12kΩ, D1+D2, T <sub>A</sub> =25°C		1.5		А
		100mA each channel, T <sub>A</sub> = 25°C		2		%
Output Current Matching		750mA each channel, T <sub>A</sub> = 25°C		2		%
LED Short Checking Current	I <sub>SHORT</sub>			2.5		m/
Control						<u> </u>
ENF, ENM Pin Logic Low Threshold	V <sub>IL</sub>				0.6	V
ENF, ENM Pin Logic High Threshold	V <sub>IH</sub>		1.5			V
ENF Internal Pull-Down Resistance	R <sub>PD(ENF)</sub>			330		kΩ
ENM Internal Pull-Down Resistance	R <sub>PD(ENM)</sub>			330		kΩ
Junction Thermal Shutdown Threshold				145		°C
Junction Thermal Shutdown Hysteresis				20		°C
Delay Time To Shutdown Status In Mov	ie/Torch Mod	le (For PWM Dimming LED Current	t)			
Delay Time	t <sub>D</sub>			3		ms
V <sub>TH</sub> To Reduce LED Current					7	•
V <sub>TH</sub>	$V_{TH}$			3.4		V
Flash Timer						
Hardware Flash Timer	t <sub>TIME</sub>			600		ms

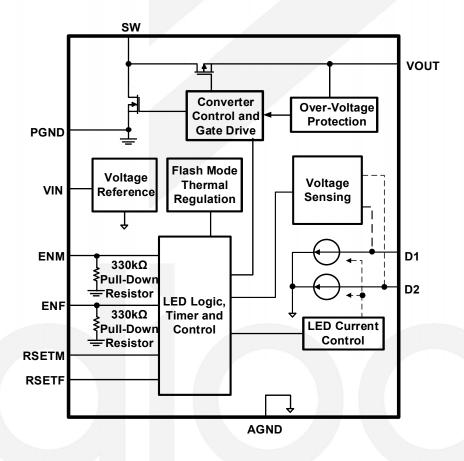


## **Typical Application**



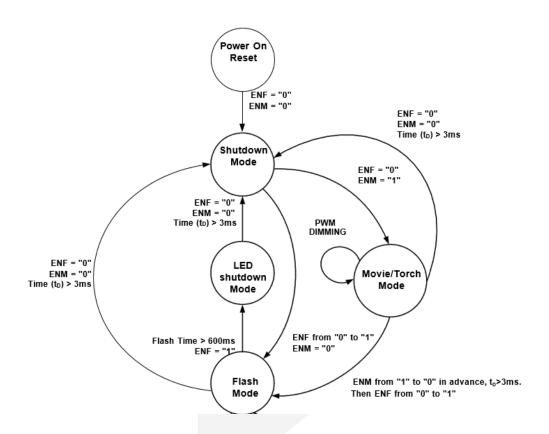


### **FUNCTIONAL BLOCK DIAGRAM**





### STATE DIAGRAM



### **Application Information**

The DIO5182 is a very high switching frequency step-up (boost) flash LED driver. Two current regulating devices are integrated to drive up to 2 flash LEDs.

The voltage step-up is accomplished by a boost topology, using an inductor-based DC/DC switching converter, in which the inductor serves as an energy storage device. By integrating optimized power MOSFETs, the DIO5182 internal switching frequency is 2MHz while still maintaining high power efficiency. Unlike a traditional DC/DC boost converter with a fixed output voltage, the DIO5182 dynamically changes its output voltage depending on the flash LED forward voltage and current. The use of unique control schemes maintains accurate current regulation in each of the two current sinks while leaving the output voltage at a minimum, increasing the overall conversion efficiency. The internal step-up converter boosts the output voltage high enough to drive the LEDs with the highest forward voltage. The two current sinks can be shorted together to drive a higher current single flash LED, sinking up to 1.5A combined.

The control interface is designed for maximum design flexibility and compatibility with various types of system controls. When the ENF is pulled high while the ENM is low, the LED current will be ramped up to the Flash mode current level which is programmed by Rsetf resistor. When ENM is pulled high while the ENF is low, the LED current will be ramped up to the Movie/Torch mode current level which is programmed by Rsetm resistor. However, if both ENM and ENF are high, the LED current will be set to Movie/Torch mode current. The driver IC and the flash LEDs will be shutdown when both ENF and ENM are at logic low.



#### Flash Mode LED Current

D1 and D2 Flash mode LED current can be programmed up to a maximum total current of 1.5A or up to 0.75A per channel. The sink current in D1 and D2 are internally matched in the DIO5182. The Flash mode current in each channel is set by the Rsetf resistor. For the desired Flash mode current in each output, the resistor value can be calculated using the following equation:

$$I_{FLASH (D1)} = I_{FLASH (D2)} = 9000/R_{SETF}$$

For DIO5182, the minimum flash time is 150ms. A flash event is initiated by asserting the ENF pin while ENM is at logic low level. A flash event is automatically terminated when ENF is dessert or when ENM is asserted. Automatic thermal regulation control is active when DIO5182 is in Flash mode. If Flash mode is enabled and the flash current is set to a high current value, the temperature of the IC can increase quickly. Once the IC's temperature goes above 100°C, the two sinks' currents will be automatically decreased according to the thermal regulation control loop. This can prevent the IC from triggering thermal shutdown and causing the LEDs to flicker. Depending on the thermal layout of the PCB and the Flash mode current setting, the DIO5182 sink current can be lower than the programmed value due to the thermal regulation protection feature.

#### **LED Short Protection**

When the DIO5182 is enabled, there is a 2.5mA (typical) LED sensing current through each current sink. It is used to detect whether either LED is shorted by generating a voltage drop through each LED. The IC internally compares the voltage difference between Vout and each sink node (D1 and D2). If this difference is below a preset threshold, the IC will treat the respective LED as shorted and disable its Flash/Movie mode current through this LED channel. However, the 2.5mA sensing current will be kept to generate the LED's voltage drop. Because some normal flash LEDs may have larger than desired leakage current (up to hundreds of micro-amps) even it's not fully turned on, this 2.5mA sensing current can guarantee that a properly functioning LED will not mistakenly be treated as a shorted LED. If the short circuit is removed during operation, the channel will automatically recover to the programmed current setting.

#### **LED Open Protection**

In case of LED open, the open channel will control the loop first so that VouT will reach OVP (approximately 5.3V), and then DIO5182 will automatically detect which channel's LED is open and disable that channel. From that point, the other channel with properly operating LED will control the loop and VouT will be regulated down to a normal operating voltage. This protection feature avoids unnecessary power consumption in the current sink by regulating the output voltage at the lowest level possible to maintain regulation for the active channel. Not only does this protect from open LEDs failures, but also allows only single flash LED operation with the unused channel floating or open. Open-circuit LED fault protection is reset when the IC is powered down and up again.

#### **Movie/Torch Mode LED Current**

D1 and D2 Movie/Torch mode LED current can be programmed up to a maximum total current of 400mA or up to 200mA per channel. Just as in Flash mode operation, the output currents in D1 and D2 are internally matched. The Movie/Torch mode current in each channel is set by the Rsetm resistor. For the desired Movie/Torch mode current in each output, the resistor value can be calculated using the following equation:

$$I_{MOVIE (D1)} = I_{MOVIE (D2)} = 7500/R_{SETM}$$

A Movie/Torch mode event is initiated by asserting the ENM pin. For additional flexibility, a lower Movie/Torch mode current than the value calculated above can be realized by applying a PWM dimming signal at ENM pin while ENF is



held low. The average Movie/Torch mode current will be proportional to the PWM duty ratio.

#### **Inductor Selection**

The DIO5182 is designed to use a  $1.0\mu\text{H}$  to  $2.2\mu\text{H}$  inductor. To prevent core saturation, ensure that the inductor-saturation current rating exceeds the peak inductor current for the application. The worst-case peak inductor current can be calculated with the following formula:

$$I_{\textit{PEAK}(L)} = \frac{V_{\textit{O(MAX)}} \times I_{\textit{LED(MAX)}}}{0.8 \times V_{\textit{IN(MIN)}}} + \frac{V_{\textit{IN(MIN)}} \times t_{\textit{ON(MAX)}}}{2 \times L}$$

Where 0.8 is the estimated efficiency of 80%. For example, for a 1.5A total (or 0.75A per channel) LED current, the peak inductor current for a 1.0µH inductor could be as high as (estimated 50% as the maximum duty ratio at the minimum input voltage, maximum LED forward voltage and maximum load current conditions):

$$I_{PEAK(L)} = \frac{4V \times 1.5A}{0.8 \times 3.5V} + \frac{3.5V \times 0.25}{2 \times 1} = 2.6A$$

If the inductor value is smaller, the inductor peak current will increase. To maintain stable operations for the boost converter, the inductor peak current must be less than both the DIO5182 current limit threshold (2.9A TYP) and the inductor saturation current rating. Manufacturer's specifications of inductors list both the inductor DC current rating, which is a thermal limitation, and peak inductor current rating, which is determined by the saturation characteristics. Measurements at full load and high ambient temperature should be performed to ensure that the inductor does not saturate or overheat due to its parasitic resistance. Bench measurements are recommended to confirm actual inductor peak current IPEAK and to ensure that the inductor does not saturate at maximum LED current and minimum input supply voltage.

#### **Recommend Power Inductor and Parameters**

Manfacturer	P/N	Inductance	DCR	Isat(A)		Irms(A)		Dimension
Marilacturei		uH	Ω	MAX	TPY	MAX	TYP	mm
Sunlord	WPN201610H1R0MT	1.0±20%	0.075	3.35	3.85	2.05	2.35	2.0*1.6*1.0
Sunlord	WPN252010H1R0MT	1.0±20%	0.076	3.1	3.5	2.5	2.9	2.5*2.0*1.0

#### **LED Current Control When Vin < 3.4V**

In order to protect battery damaging by big LED current in low battery voltage status, DIO5182 can linearly reduce the LED current; the control curve is shown in Figure 2.

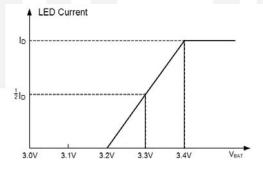


Figure 2. When  $V_{BAT}$  < 3.2V, No LED Current Output



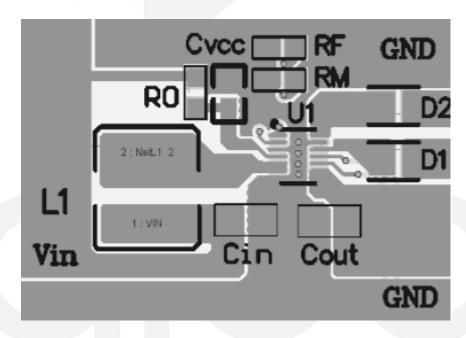
#### **Capacitor Selection**

For good input voltage filtering low ESR ceramic capacitors are recommended. At least a 2.2µF input capacitor is recommended for high current flash LEDs to improve transient behavior of the regulator and EMI behavior of the total power supply circuit. The input capacitor should be placed as close as possible to the input pin and the PGND pin of the DIO5182. The output capacitance required depends on the required LED current. A 2.2µF or 4.7µF ceramic capacitor works well in most situations.

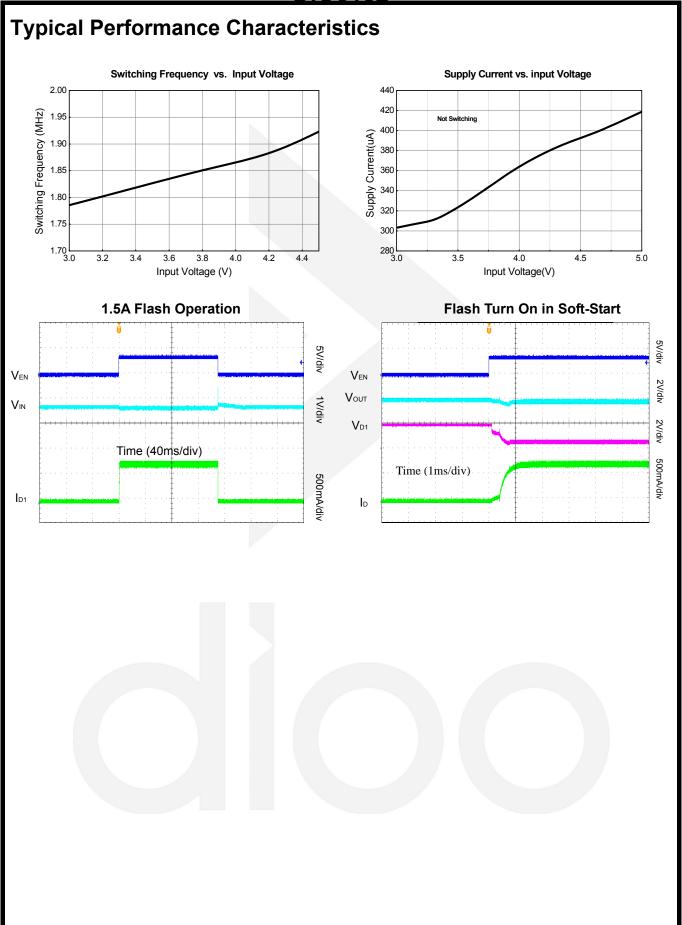
#### **Layout Guidelines**

It is very important to PCB layout, especially to high switching transition and high current converter. Careful PCB layout is required, or the regulator maybe happen unstable problem, as well as EMI problem. Therefore, wide and short traces will be considered for the main switching current paths and ground. The below guide lines will be recommended.

- Input capacitor, output capacitor, inductor and flash LED should be placed as possible as close to the DIO5182 chip.
- Input and output capacitors ground should be placed as possible as close to GND PIN, and wide traces will be recommended as well.
- 3. Inductor should be placed as possible as close to SW PIN, and wide traced will be recommended as well.
- 4. Flash LED should be placed as possible as close to D1/D2, and wide traced will be recommended as well.
- 5. Analog trace, such as RSETM and RSETF, should be routed far away from SW areas.
- 6. Ground nodes should be placed as possible as close to GND PIN.

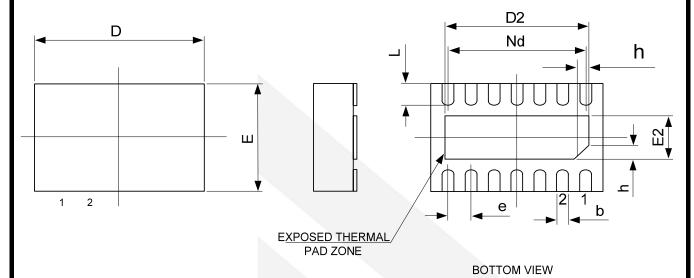


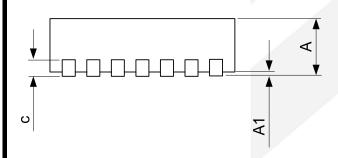






# Physical Dimensions: DFN-14 3\*2





COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)							
Symbol	MIN	MAX					
Α	0.70	0.75	0.80				
A1	-	0.02	0.05				
b	0.15	0.18	0.25				
С	0.18	0.25					
D	2.90	3.00	3.10				
D2	2.40 2.50		2.60				
е	0.40BSC						
Nd	2.40BSC						
E	1.90	2.00	2.10				
E2	0.70	0.90					
L	0.30	0.35	0.40				
h	0.20	0.25	0.30				



### **CONTACT US**

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